

S8050

NPN TRANSISTOR

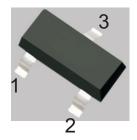
FEATURES

- Complimentary to \$8550
- Collector Current: IC=0.5A

MAXIMUM RATINGS (Ta=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Collector–Base Voltage	Vсво	40	V
Collector–Emitter Voltage	Vceo	25	V
Emitter-Base Voltage	VEBO	5	V
Collector Current — Continuous	Ic	500	mA
Collector Power Dissipation	Pc	300	mW
Thermal Resistance From Junction To Ambient	RthJA	417	°C/W
Operation Junction and Storage Temperature Range	TJ,Tstg	-55~+150	°C

SOT-23



1.BASE 2.EMITTER 3.COLLECTOR

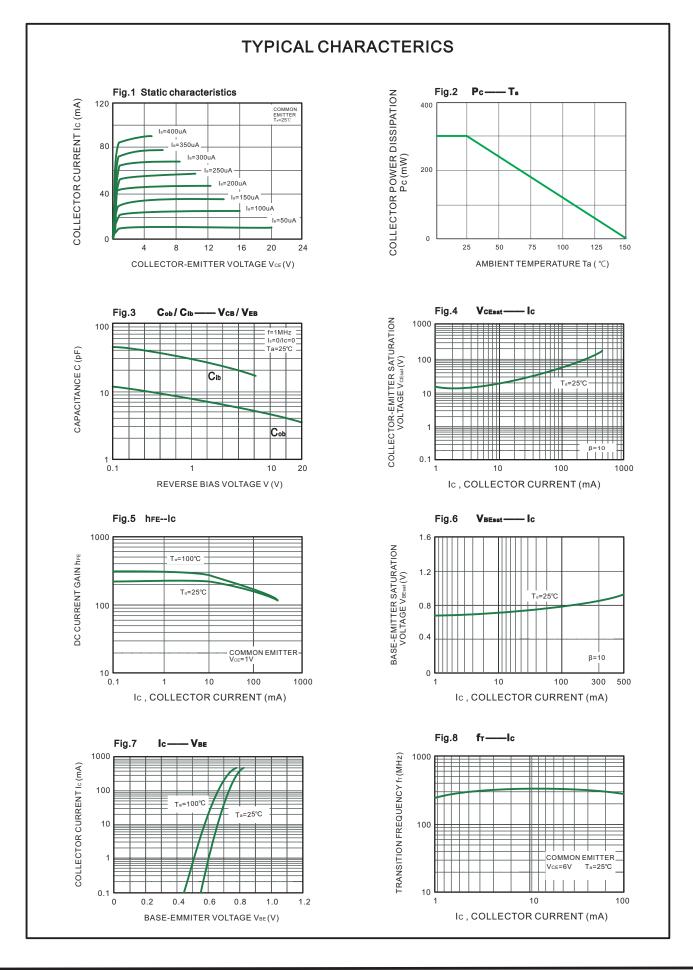
CLASSIFICATION OF hfe1

Rank	L	Н	J
Range	120-200	200-350	300-400

ELECTRICAL CHARACTERISTICS (TA = 25°C unless otherwise noted.)

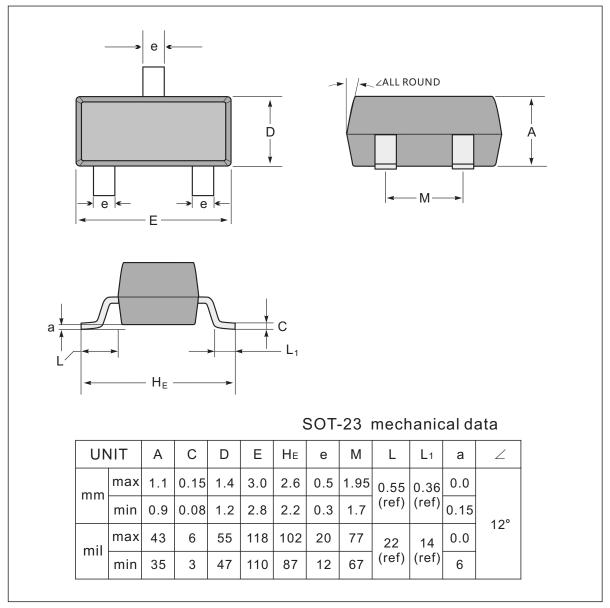
Parameter		Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	Ic = 100uA, IE = 0	40			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	Ic = 1 mA, I _B = 0	25			V
Emitter-base breakdown voltage		IE = 100uA, Ic = 0	5			V
Collector cut-off current	Ісво	V _{CB} = 40V, I _E = 0			0.1	uA
Collector cut-off current	Iceo	VcE = 20V, IB=0			0.1	uA
Emitter cut-off current	ІЕВО	VEB = 5V, IC =0			0.1	uA
DC current gain	h _{FE1}	VcE = 1V, Ic = 50mA	120		400	
	h _{FE2}	VcE = 1V, Ic = 500mA	50			
Collector-emitter saturation voltage	V _{CE(sat)}	Ic = 500mA, IB = 50mA	500mA, I _B = 50mA		0.6	V
Base-emitter saturation voltage	V _{BE(sat)}	Ic = 500mA,I _B =50mA			1.2	V
Transition frequency	f⊤	VcE = 6V, Ic = 20mA, f=30MHz	150			MHz



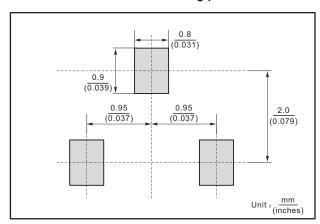




SOT-23 Package Outline Dimensions



The recommended mounting pad size



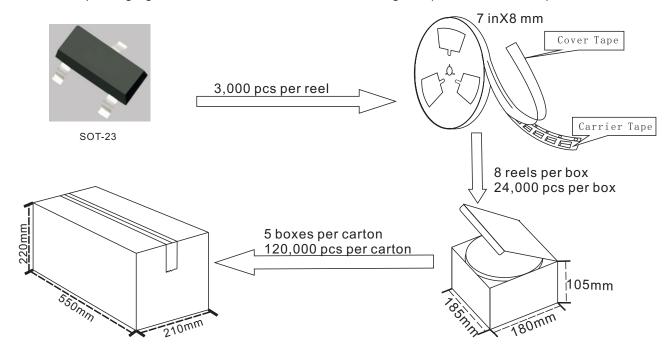
Marking

Type number	Marking code				
S8050	J3Y				

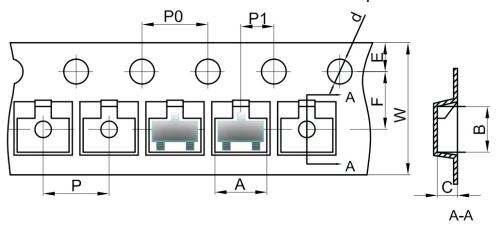


SOT-23 Packing

1. The method of packaging and dimension are shown as below figure. (Dimension in mm)



SOT-23 Embossed Carrier Tape



Dimensions are in millimeter										
Pkg type	Α	В	С	d	E	F	P0	Р	P1	W
SOT-23	3.15	2.77	1.22	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

SOT-23 Tape Leader and Trailer

